

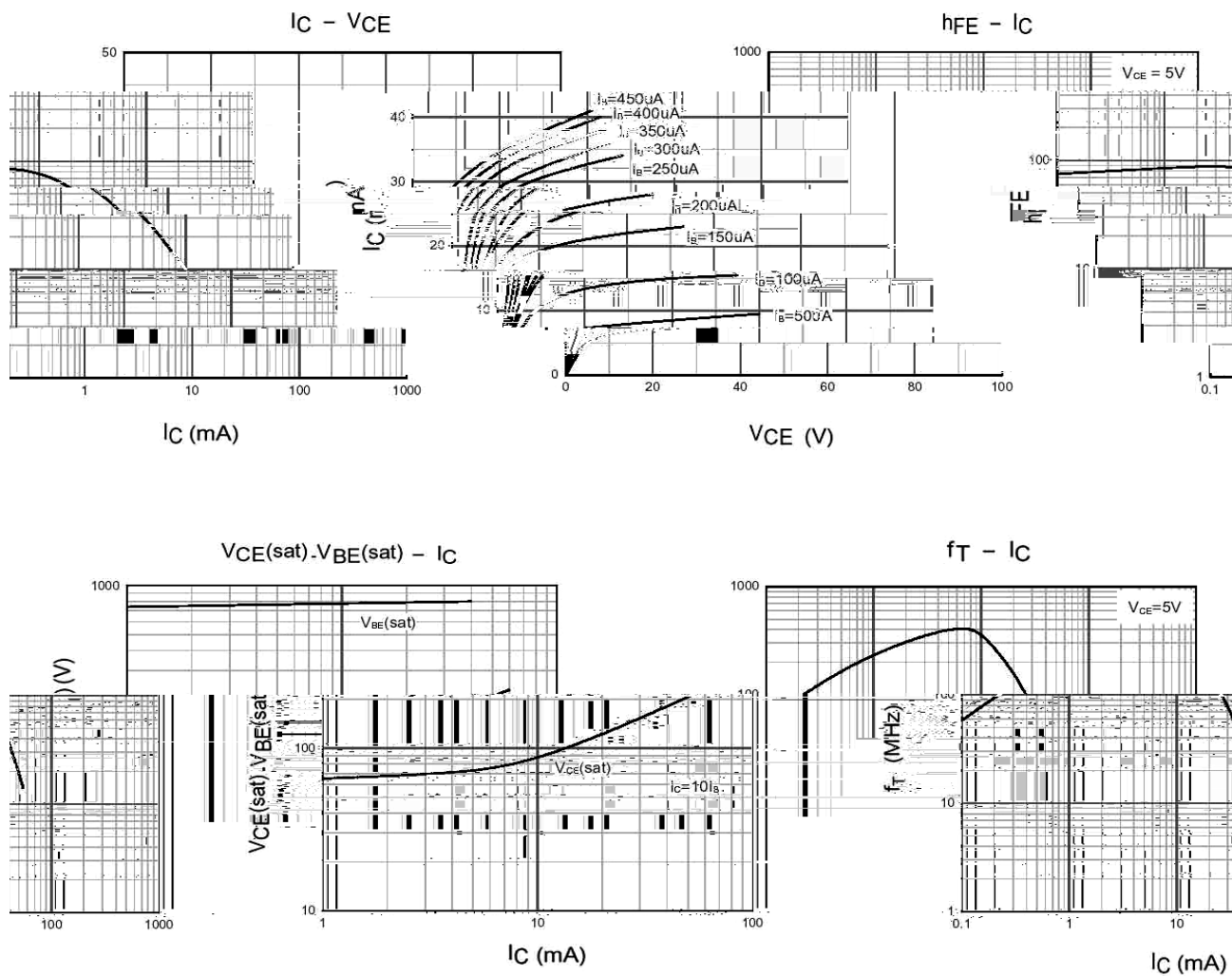
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	50	V
Collector to Emitter Voltage	V_{CEO}	30	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current	I_C	30	mA
Base Current	I_B	10	mA
Collector Power Dissipation	P_C	310	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=0.1mA$ $I_E=0$	50			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=1.0mA$ $I_B=0$	30			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=0.1mA$ $I_C=0$	5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=50V$ $I_E=0$			0.1	A
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5.0V$ $I_C=0$			0.1	A
DC Current Gain	h_{FE}	$V_{CE}=5.0V$ $I_C=1.0mA$	28		198	
Collector-Emitter Saturation voltage	$V_{CE(sat)}$	$I_C=10mA$ $I_B=1.0mA$		0.08	0.3	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=5.0V$ $I_C=1.0mA$		0.7	0.75	V
Current Gain Bandwidth Product	f_T	$V_{CE}=5.0V$ $I_C=1.0mA$	150	370		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V$ $I_E=0$ $f=1.0MHz$		1.5		pF
Noise Figure	NF	$V_{CE}=5.0V$ $I_C=1.0mA$ $R_g=500$ $f=1.0MHz$		2.0	4.0	dB

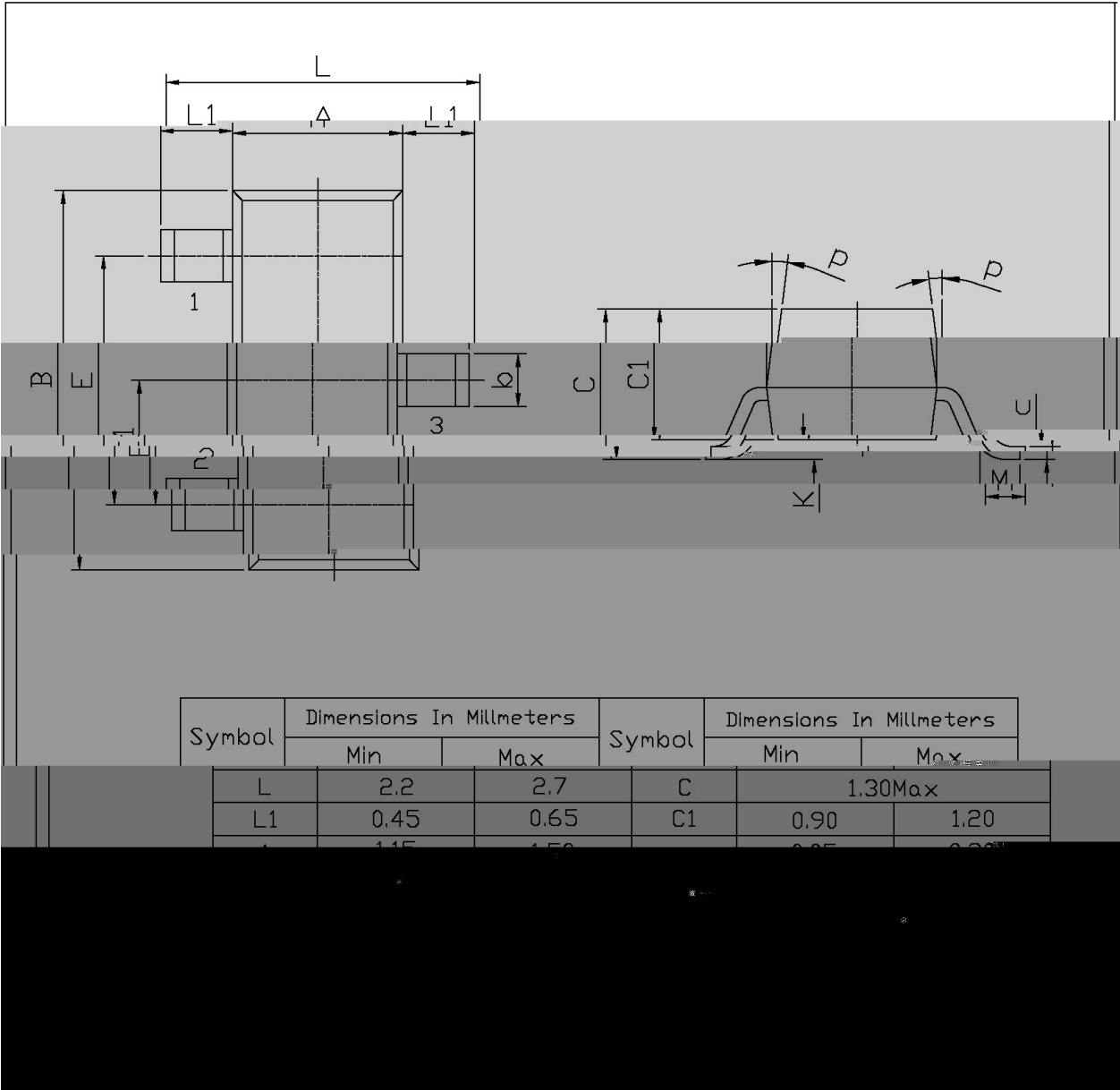
/ Electrical Characteristic Curve



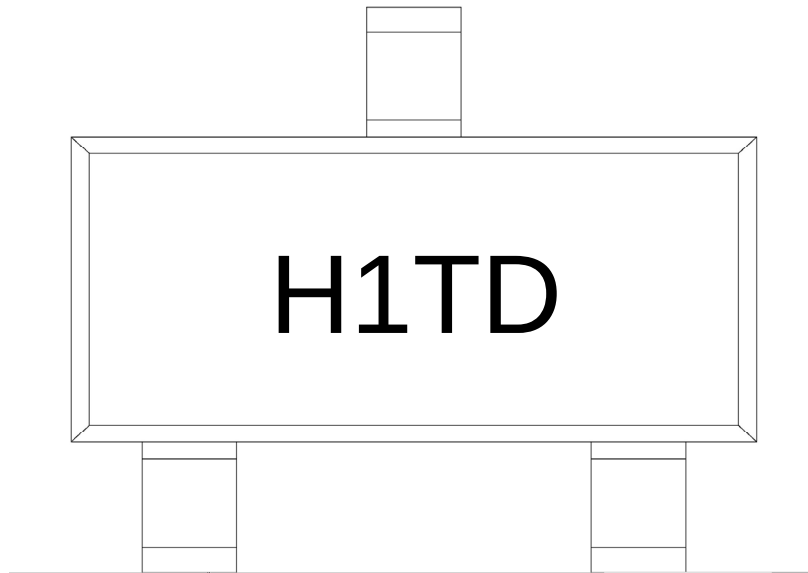
/ Package Dimensions

SOT-23

单位：mm



/ Marking Instructions



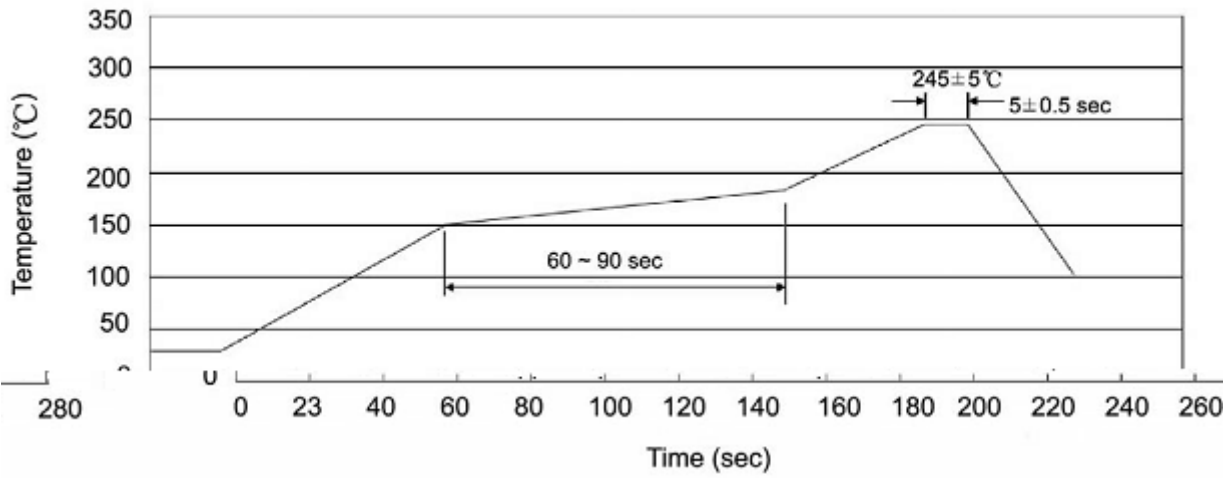
Note:

Company Code

Product Type Code

h_{FE} Classifications Symbol Code

() /



Note:

1

25 150

60 90sec;

1.Preheating:25~150 , Time:60~90sec.

2

245 5

5 0.5sec;

2.Peak Temp.:245 5 , Duration:5 0.5sec.

3

2 10 /sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260 5

10 1 sec.

Temp.:260±5

Time:10±1 sec

/ Packaging SPEC.

Tw260±j/TT4 1 53e3089b 1R 1 742(E 1 c0 E 1 c0 L 1 607287j/007